

# iscN-Channel MOSFET Transistor

TK6A60D

### • FEATURES

- Low drain-source on-resistance:
  R<sub>DS</sub>(ON) = 1.25Ω (MAX)
- Enhancement mode:
  Vth = 2 to 4V (VDS = 10 V, ID=1.0mA)
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### DESCRITION

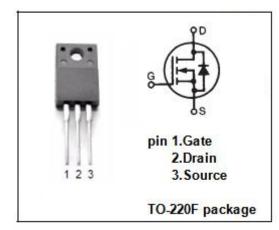
· Switching Voltage Regulators

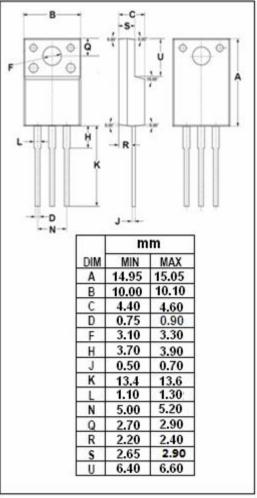
### • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V <sub>DSS</sub>	Drain-Source Voltage	600	<b>V</b>
V <sub>GS</sub>	Gate-Source Voltage	±30	V
ΙD	Drain Current-Continuous	6	Α
I <sub>DM</sub>	Drain Current-Single Pulsed	24	А
$P_D$	Total Dissipation @T <sub>C</sub> =25℃	40	W
Tj	Max. Operating Junction Temperature	150	$^{\circ}$
T <sub>stg</sub>	Storage Temperature	-55~150	

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
Rth(ch-c)	Channel-to-case thermal resistance	3.125	°C/W







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#### **ELECTRICAL CHARACTERISTICS**

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> = 10mA	600			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = 10V; I <sub>D</sub> =1.0mA	2		4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =3A			1.25	Ω
lgss	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> = 0V			±1	μА
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =600V; V <sub>GS</sub> = 0V			10	μА
$V_{SDF}$	Diode forward voltage	$I_{DR}$ =6A, $V_{GS}$ = 0 V			1.7	V



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